

The PJ494 incorporates on a single monolithic chip all the functions required in the construction of a pulse-width-modulation control circuit. Designed primarily for power supply control, these devices offer the systems engineer the flexibility to tailor the power supply control circuitry to his application.

The PJ494 contains an error amplifier, an on-chip adjustable oscillator, a deed-time control comparator, pulse-steering control flip-flop, a 5-volt, 5% precision regulator, and output-control circuits. The error amplifier exhibits a common-mode voltage from -0.3 volts to Vcc -2 volts. The dead-time control comparator has a fixed offset that provides

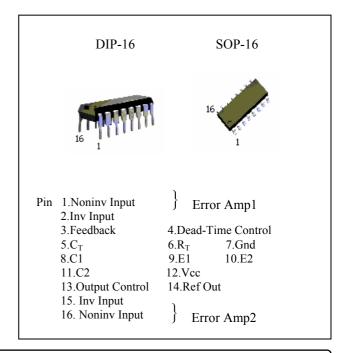
approximately 5% dead time when externally altered. The onchip oscillatory be bypassed by terminating R_T (pin 6) to the reference output and providing a sawtooth input to C_T (PIN 5), or it may be used to drive the common circuits in synchronous multiple-rail power supplies. The uncommited output transistor provide either common-emitter or emitter-follower output capability. Each device provides for push-pull or single-ended output operation, which may be selected through the output-control function. The architecture of these devices prohibits the possibility of either output being pulsed twice during push-pull operation.

FEATURES

- Complete PWM Power Control Circuitry
- Uncommitted Outputs for 200mA Sink or Source Current
- Output Control Selects Single-Ended or Push –Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Variable Dead-Time Provides Control over Total Range
- Internal Regulator Provides a Stable 5-V Reference Supply, 5%

ORDERING INFORMATION

Device	OperatingTemperature	Package
	(Ambient)	
PJ494CD	20°C 40 105°C	DIP-16
PJ494CS	-20°C to +85°C	SOP-16



ABSOLUTE MAXIMUM RATINGS OVER OPERATING FREE-AIR TEMPERATURE RANGE

(unless otherwise noted)

Rating	Symbol	Value	Unit
Supply voltage	Vcc	41	V
Amplifier input voltage	Vi	Vcc+0.3	
Collector output voltage	Vo	41	
Collector output current		250	mA
Operating free-air temperature range		-20 to 85	
Storage temperature range	$T_{ m stg}$	-25 to 125	$^{\circ}\mathrm{C}$
Operating Junction Temperature	Тл	125	
Lead temperature 1,6mm from case for 10 seconds		260	
Power Dissipation @Ta≤45°C	PD	1000	mW

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RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Max	Unit
Supply voltage	Vcc	7	40	V
Amplifier input voltage	Vi	-0.3	Vcc-2	
Collector output voltage	Vo		40	
Collector output current(each transistor)			200	mA
Current into feedback terminal			0.3	
Timing capacitor	C_{T}	0.47	10000	nF
Timing resistor	R_{T}	1.8	500	ΚΩ
Oscillator frequency		1	300	KHz
Operating free-air temperature	T_{A}	0	70	$^{\circ}\mathbb{C}$

ELECTRICAL CHARACTERISTICS OVER RECOMMENDED OPERATING FREE-AIR TEMPERATURE

Vcc=15V, f=10KHz (unless otherwise noted).

REFERENCE SECTION

Dovomotov	Test Conditions*		Unit		
Parameter		Min	Тур	Max	
Output voltage(Vref)	Io=1mA	4.75	5	5.25	V
Line regulation	Vcc=7V to 40V		2.0	25	mV
Load regulation	Io=1mA to 10mA		3.0	15	111 V
Output voltage change with temperature	ΔT_A =MIN to MAX		0.2	1	%
Short-circuit output current***	Vref=0	15	35	75	mA

OSCILLATOR SECTION

Parameter	Test Conditions*	Value			Unit
rarameter	Test Conditions."	Min	Тур	Max	
Frequency	$C_T = 0.001 \mu F, R_T = 30 \text{K}\Omega$		40		KHz
Standard deviation of frequency****	$C_T = 0.001 \mu F, R_T = 30 K\Omega$		3.0		
Frequency change with voltage	Vcc=7V to 40V, T_A =25°C		0.1		%
Frequency change with temperature***	$C_T = 0.001 \mu F, R_T = 30 \text{K}\Omega$			12	70
	ΔT_A =MIN to MAX				

ERROR AMPLIFIER SECTION

Parameter	Test Conditions*		Value		
		Min	Typ**	Max	
Input offset voltage	Vo=(pin 3)=2.5V		2.0	10	mA
Input offset current	Vo=(pin 3)=2.5V		5.0	250	nA
Input bias current	Vo=(pin 3)=2.5V		-0.1	-1.0	μA
Common-mode input voltage range	Vcc=7V to 40V		-0.3 toV _{cc} -2		V
Open-loop voltage amplification	Δ Vo=3V,R _L =2K Ω ,Vo=0.5 to 3.5V	70	95		dB
Unity-gain bandwidth	$R_L=2K\Omega$, $Vo=0.5$ to 3.5 V		800		KHz
Common-mode rejection ratio	ΔVo=40V, T _A =25°C	65	90		dB
Power Supplu Rejection Ratio	$\Delta Vcc=33V, Vo=2.5V, R_L=2K\Omega$		100		dB
Output sink current (pin 3)	V_{ID} =-15mV to -5V, $V_{(PIN3)}$ =0.7V	0.3	0.7		mA
Output source current (pin 3)	$V_{ID}=15 \text{mV to } 5V, V_{(PIN3)}=3.5V$	2.0	-4.0		mA

OUTPUT SECTION

Parameter		Test Conditions	Value			Unit
			Min	Тур	Max	
Collector off-state current		$V_{CE} = 40V, V_{CC} = 40V$		2.0	100	μΑ
Emitter off-state current		$Vcc=Vc=40V, V_E=0$			-100	
Collector-emitter saturation	Common-emitter	V_E =0, Ic=200mA		1.1	1.3	V
voltage	Emitter-follower	$Vc=15V, I_E=-200mA$		1.5	2.5	
Output control input current		V _I =Vref			3.5	mA



DEAD-TIME CONTROL SECTIONDead-time control-section (See Figure 11)

Parameter	Test Conditions		Unit		
		Min	Typ*	Max	
Input bias current (pin 4)	V_{I} =0 to 5.25V		-2.0	-10	μΑ
Maximum duty cycle, each output	$V_I(pin 4)=0, C_T=0.1 \mu F, R_T=12 K\Omega$		45	50	%
Input threshold voltage(pin 4)	Zero duty cycle		3.0	3.3	17
	Maximum duty cycle	0			V

PWM COMPARATOR SECTION (See Figure11)

Parameter	Test Conditions	Value			Unit
		Min	Typ*	Max	
Input threshold voltage (pin 3)	Zero duty cycle		4.0	4.5	V
Input sink current (pin 3)	V(pin 3)=0.7V	0.3	0.7		mA

TOTAL DEVICE

Parameter	Test Conditions		Value			Unit
			Min	Typ*	Max	
Standby supply current	Pin 6 at Vref, all other inputs and	Vcc=15V		6.0	10	mA
	outputs open	Vcc=40V		9.0	15	
Average supply current	V _{I(PIN4)} =2V, See Figure 1			7.5		

SWITCHING CHARACTERISTICS, T_A=25°C

Parameter	Test Conditions	Value			Unit
		Min	Typ*	Max	
Output voltage rise time	Common-emitter configuration,		100	200	ns
Output voltage fall time	See Figure 3		25	100	
Output voltage rise time	Emitter-follower configuration,		100	200	
Output voltage fall time	See Figure 4		40	100	

UNDERVOLTAGE LOCKOUT SECTION

UNDER VOLTAGE EC	CROUT SECTION				
Parameter	Test Conditions		Value		
		Min	Typ*	Max	
Turn-on Threshold	Vcc increasing Iref=1.0mA	5.5	6.43	7.0	V

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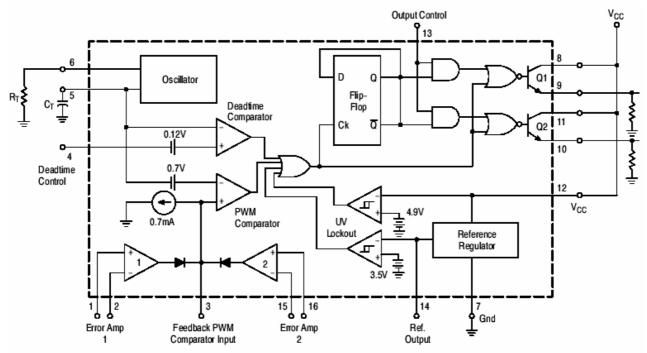
- All typical value except for temperature coefficient are at $T_A=25^{\circ}C$
- For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
- All typical values except for parameter changes with temperature are at $T_A=25^{\circ}C$
- Duration of the short-circuit should not exceed one second
- Standard deviation is a measure of the statistical distribution about the mean as derived from the formula

$$\sigma = \left[\sum_{n=1}^{N} \frac{(x_n - \overline{x})^2}{N - 1}\right]^{\frac{1}{2}}$$

• Temperature coefficient of timing capacitor and timing resistor not taken into account



FUNCTION BLOCK DIAGRAM



This device contained 46 active transistors

Figure 1. Representative Block Diagram

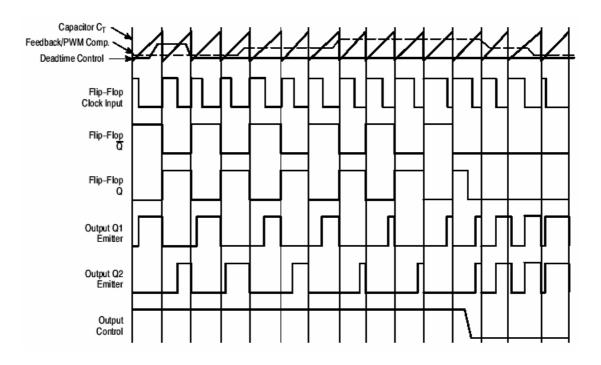


Figure 2. Timing Diagram



APPLICATIONS INFORMATION

Description

The PJ494 is a fixed-frequency pulse width modulation control circuit, incorporating the primary building blocks required for the control of a switching power supply. (See Figure 1.) An internal-linear sawtooth oscillator is frequescy-programmable by two external components, RT and CT. The approximate oscillator frequency is determined by:

$$f_{osc} \approx \frac{1.1}{R_T \bullet C_T}$$
 For more information refer to Figure 3.

Output pulse width modulation is accomplished by comparison of the positive sawtooth waveform across capacitor CT to either of two control signals. The NOR gates, which drive output transistors Q1 and Q2, are enabled only when the flip-flop clock-input line is in its low state. This happens only during that portion of time when the sawtoothvoltage is greater than the control signals. Therefore, an increase in contro-signal amplitude causes a corresponding linear decrease of output pulse width. (Refer to the Timing Diagram shown in Figure 2.)

The control signals are external inputs that can be fed into the deadtime control, the error amplifier inputs, or the feedback input. The deadtime control comparator has an effective 120mV input offset which limits the minimum output deadtime to approximately tge first 4% of the sawtooth-cycle time. This would result in a maximum duty cycle on a given output of 96% with the output control grounded, and 48% with it connected to the reference line. Additional deadtime may be imposed on the output by setting the deadtime-control input to a fixed voltage, ranging between 0V to 3.3V .

Functional lable			
Input/Output Controls	Output Function	$\frac{f_{out}}{f_{osc}} =$	
Grounded	Single–ended PWM @ Q1 and Q2	1.0	
@ V _{ref}	Push–pull Operation	0.5	

The pulse width modulator comparator provides a means for the error amplifiers to adjust the output pulse width from the maximum percent on-time, established by the deadtime control input, down to zero as the voltage at the feedback pin varies from 0.5V to 3.5V. Both error amplifiers have a common mode input range from -0.3C to (Vcc - 2V), and may be ised to sense power-supply output voltage and current. The error –amplifier outputs are active high and are ORed together at the noninverting input of the pulse-width modulator comparator. With this configuration, the amplifier that demands minimum output on time, dominates control of the loop.

When capacitor C_T is discharged, a positive pulse is generated on the output of the deadtime comparator, which clocks the pulse-steering flip=flop and inhibits the output transistors, Q1 and Q2. With the output-control connected to the reference line, the pulse-steering flip-flop directs the modulated pulses to each of the rwo output transistors alternately for push-pull operation. The output frequency is equal to half that of the oscillator. Output drive can also be taken from Q1 and Q2, when single-ended operation with a maximum on-time of less than 50% is required. This is desirable when the output transformer has a ringback winding with a catch diode ised for snubbing. When higher output-drive currents are required for single-ended operation, Q1 and Q2 may be connected in parallel, and the output mode pin must be tied to ground to disable the flip-flop. The output frequency will now be equal to that of the oscillator.

The PJ494 has an internal 5.0V reference capable of sourcing up to 10mA of laod current for external bias circuits. The reference has an internal accuracy of $\pm 5.0\%$ with a typical thermal drift of less than 50mV over an operating temperature range of 0 to 70° C.

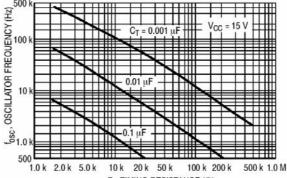


Figure 3. Oscillator Frequency versus Timing Resistance



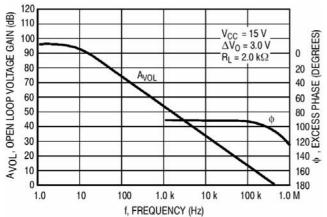


Figure 4. Open Loop Voltage Gain and Phase Versus Frequency

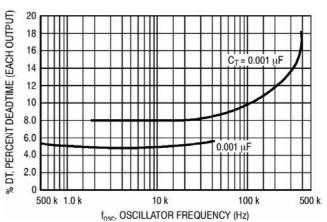


Figure 5. Percent Deadtime versus Oscillator Frequency

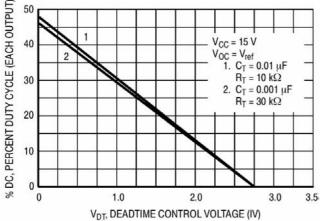
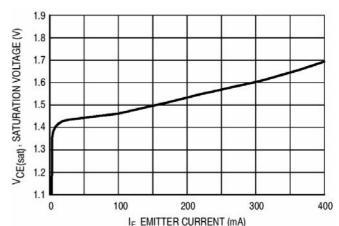


Figure 6. Percent Duty Cycle versus
Deadtime Control Voltage



I_{E.} EMITTER CURRENT (mA)
Figure 7. Emitter-Follower Configuration
Output Saturation versus Emitter Current

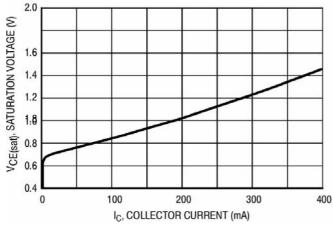


Figure 8. Common-Emitter Configuration Output Saturation Voltage versus Collector Current

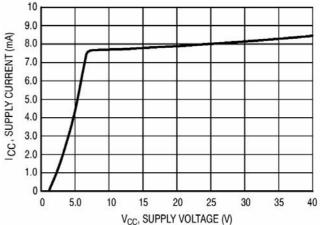
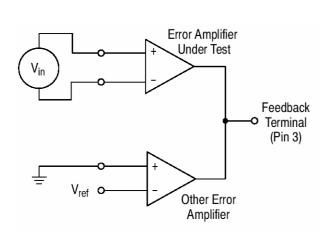


Figure 9. Standby Supply Current versus Supply Voltage

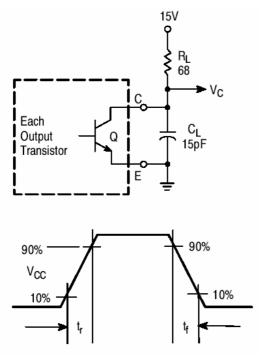


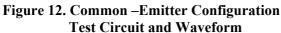


 $V_{CC} = 15V$ 150 ≹ 2W ₹ 150 2W Vcc Deadtime C1 Output 1 Test E1 Feedback C2 Output 2 RT E2 Ст Ref Output Out Control 50k Ť

Figure 10. Error-Amplifier Characteristics

Figure 11. Deadtime and Feedback Control Circuit





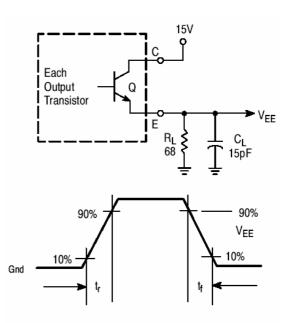
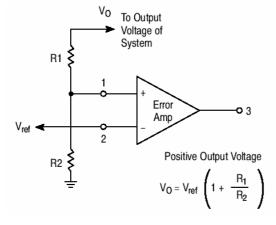


Figure 13. Emitter-Follower Configuration Test Circuit and Waveform



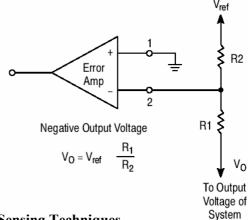
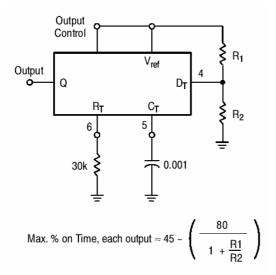


Figure 14. Error-Amplifier Sensing Techniques

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Output Q DT 4 Rs

Figure 15. Deadtime Control Circuit

Figure 16. Soft-Start Citcuit

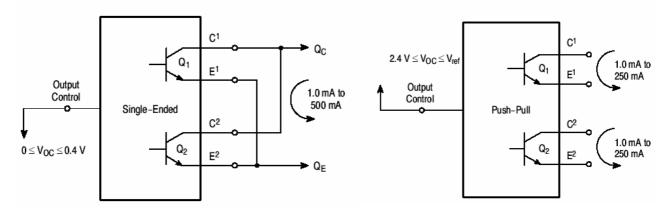


Figure 17. Output Connections for Single-Ended and Push-Pull Configurations

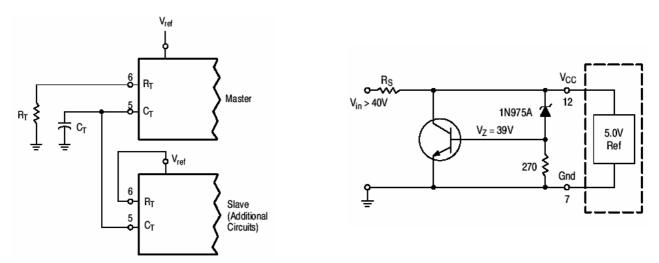


Figure 18. Slaving Two or More Control Circuit

Figure 19. Operation With VIN >40V Using External Zener

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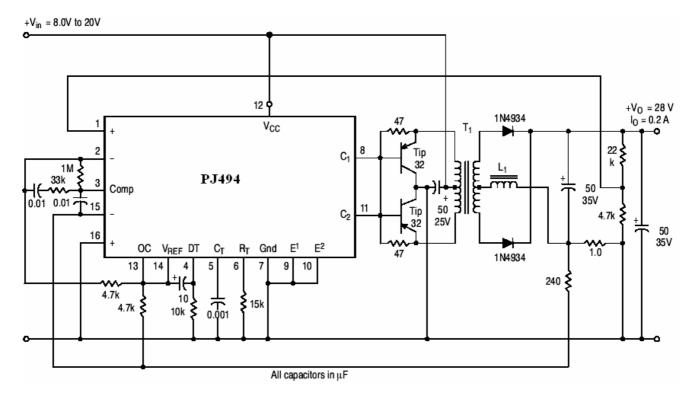


Figure 20. Pulse Width Modulated Push-Pull Converter

Test	Condition	Result
Line Regilation	$V_{IN} = 10V$ to $40V$	14mV 0.28%
Load Regilation	$V_{IN} = 28V$, Io =1.0mA to 10A	3.0mV 0.06%
Output Ripple	$V_{IN} = 28V$, $I_{O} = 1.0A$	65mV pp P.A.R.D
Short Circuit Current	$V_{IN} = 29V, R_{L}=0.1\Omega$	1.6A
Efficiency	$V_{IN} = 28V$, Io =1.0A	71%

L1 – 3.5mH @ 0.3A

T1 – Primary: 20T C.T. #28 AWG Secondary: 120T C.T. #36 AWG Core: Ferroxcube 1408P-L00-3CB

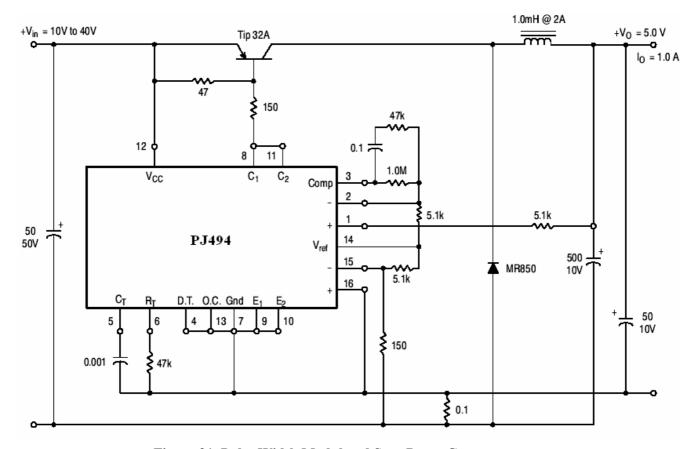


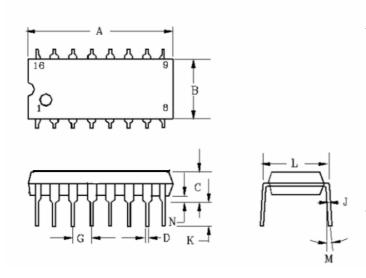
Figure 21. Pulse Width Modulated Step-Down Converter

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Test	Condition	Result
Line Regulation	$V_{IN} = 8.0 V$ to $40 V$	3.0mV 0.01%
Load Regulation	$V_{IN} = 12.6V$, $Io = 0.2mA$ to $200mA$	5.0mV 0.02%
Output Ripple	$V_{IN} = 12.6V$, $I_0 = 200mA$	40mV pp P.A.R.D
Short Circuit Current	$V_{IN} = 12.6V, R_L = 0.1\Omega$	250mA
Efficiency	$V_{IN} = 12.6V$, $Io = 200mA$	72%

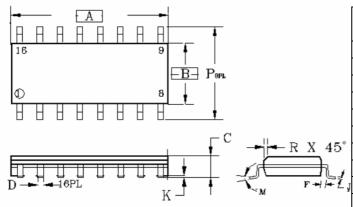


DIP-16



	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	17.80	18.05	0.701	0.710
В	6.25	6.45	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
G	1.27BSC		0.05BSC	
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
L	0°	7°	0°	7°
M	-	10°	0.395	0.415

SOP-16



	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
В	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27BSC		0.05BSC	
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029